# 500mA, 500KHz PWM Synchronous Boost Converter with Output Isolated During Shutdown

#### **General Description**

The EMH7020 is a high efficiency, synchronous fixed frequency, current-mode step-up DC/DC converter. During shutdown mode, the output is completely isolated from the input without drawing any battery current. The fixed 500KHz switching frequency obtains maximum efficiency up to 96% and uses only a few external components.

With  $180\Omega$  loading, the minimum start-up voltage can be as low as 0.93V, provided by a one or two-cell alkaline or one-cell Li-Lon battery.

The features of EMH7020 include current limit, low battery comparator, open-drain power good output, short circuit, and thermal shutdown protection. The EMH7020 is also available in 3X3mm TDFN-10 and E-MSOP-8L package.

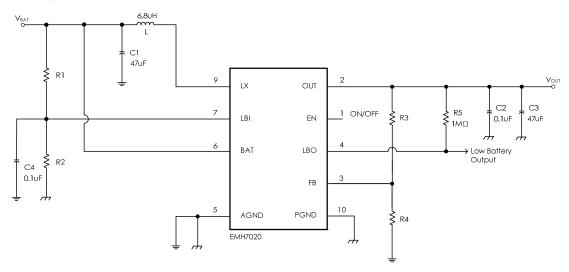
#### **Applications**

- Mobile Phone
- Digital Still Cameras
- Portable applications
- MP3 Players
- GPS Receivers

#### **Features**

- Up to 96% efficiency
- Reference voltage: 0.5V
- Output to input disconnect at shutdown mode
- 500mA current delivery
- Switch current limit protection
- 500KHz fixed switching frequency
- Thermal shutdown protection
- 0.5V Low-battery comparator
- Min-start up voltage: 0.93V
- Low quiescent current: 50uA (Tpy.)
- Low shutdown current < 1uA
- TDFN 3x3mm 10 pins and E-MSOP 8 pins package

#### **Typical Application**



Elite Semiconductor Memory Technology Inc./Elite MicroPower Inc.

Publication Date: Jun. 2012 Revision: 1.2 1/15

### **Connection Diagrams**

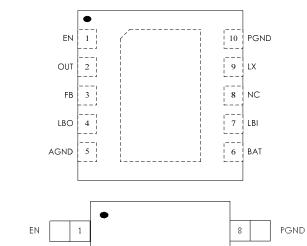
OUT

FB

AGND

3

4



#### Order information

EMH7020-X XX	(XFF10NRR Output voltage
00	Adj output
FF10	TDFN-10 Package
NRR	RoHS & Halogen free package Rating: -40 to 85°C Package in Tape & Reel

EMH7020-> XX	(XME08NRR Output voltage
00	Adj output
ME08	E-MSOP-8L Package
NRR	RoHS & Halogen free package Rating: -40 to 85°C Package in Tape & Reel

#### Order, Marking & Packing Information

E-MSOP-8L

Package	Product ID.	Marking	Packing
TDFN-10	EMH7020-00FF10NRR	EMP EMH7020 Tracking Code  1 2 3 4 5	Tape & Reel 5Kpcs
E-MSOP-8L	EMH7020-00ME08NRR	EMP EMH7020 Tracking code  PINI DOT  1 2 3 4	Tape & Reel 3Kpcs

LX

TE

BAT

#### **Pin Functions**

Pin Name	TDFN-10 Pin #	E-MSOP-8L Pin #	Function
EN	1	1	Chip enable pin (1: enabled ; 0: disabled)
OUT	2	2	Boost converter output
FB	3	3	Output voltage feedback input pin, using resistor divider to set the output voltage from +1.8V to 5.5V.
LBO	4	N/A	Open-drain low battery comparator output
AGND	5	4	Analog ground
BAT	6	5	Battery input
LBI	7	N/A	Low battery comparator input It should be connected to BAT pin if the comparator is not used.
TE	N/A	6	Reserved for test mode
NC	8	N/A	NC pin
LX	9	7	Boost and rectifying switch input
PGND	10	8	Power ground
Thermal land	11	9	Must be soldered this to PCB ground to achieve appropriate power dissipation.

#### **Functional Block Diagram**

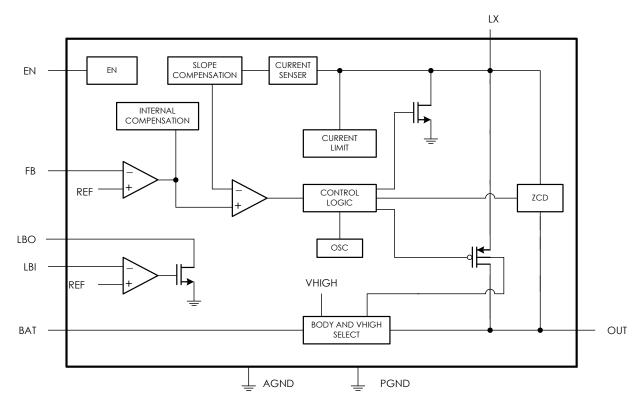


FIG.1 Functional block diagram of EMH7020

Absolute Maximum Ratings (Notes 1, 2)

BAT, EN, OUT, FB and LBO Voltage

-0.3V to 6V
LBI Voltage

-0.3V to VBAT
Lead Temperature (Soldering, 10 sec.)

LX Voltage

-0.3V to (VBAT + 0.3V)

ESD Rating

Power Dissipation(Note 5)Human Body Model2KVStorage Temperature Range-65°C to 150°CMachine model200V

Operating Ratings (Note 1, 2)

Supply Voltage ( $V_{BAT}$ ) 0.9V to 5.5V Thermal Resistance ( $\theta_{JA}$ , Note 3)) 110°C/W Operating Temperature Range -40°C to 85°C Thermal Resistance ( $\theta_{JC}$ , Note 4)) 8.5°C/W

#### **Electrical Characteristics**

Unless otherwise specified, all limits guaranteed for  $V_{OUT}$ =3.3V,  $V_{EN}$ =1.2V,  $T_A$  = 25°C; **Boldface** limits apply for the operating temperature extremes: -40°C and 85°C.

Symbol	Parameter	Conditions	Min	Typ (Note 6)	Max	Units
	Stort Up V	RL=180Ω		0.93	1.2	٧
$V_{START-UP}$	Start-Up V <sub>BAT</sub>	RL=3.3K $\Omega$		0.85		٧
V <sub>ОИТ</sub>	Output voltage		1.8		5.5	٧
$V_{FB}$	Feedback voltage		485	500	515	mV
Fsw	Operation Frequency		400	500	600	kHz
	Current limit		1.2	1.5	1.8	Α
Icı	Current limit @ start-up			0.5*I <sub>CL</sub>		А
D	ron(nmos)	$I_{SW} = 500 \text{mA}$		250		mΩ
R <sub>DS-ON</sub>	ron(pmos)	$I_{SW} = 500 \text{mA}$		330		mΩ
	Vout	VFB=0.6V		50		μA
lq	V <sub>BAT</sub>			1	3	μA
I <sub>SD</sub>	Shutdown current	VBAT≦4.2			1	μΑ
<b>T</b>	ОТР			150		$^{\circ}\mathbb{C}$
T <sub>SENSOR</sub>	hysteresis			30		$^{\circ}\!\mathbb{C}$
		( $V_{BAT}$ or $V_{OUT} > 1.8V$ )	0.9			٧
V <sub>IH</sub>		( $V_{BAT}$ or $V_{OUT}$ <1.8V)	0.9*V <sub>BAT</sub>			٧
		(V <sub>BAT</sub> or V <sub>OUT</sub> >1.8V)			0.4	٧
$V_{IL}$		(V <sub>BAT</sub> or V <sub>OUT</sub> <1.8V)			0.1*V <sub>BAT</sub>	٧
	Line regulation	I <sub>LOAD</sub> =100mA, V <sub>OUT</sub> =5.0V, V <sub>BAT</sub> =2.4V to 3.6V			0.6%	(Vomax-vomin)/ (Vimax-vimin)
	Load regulation	V <sub>BAT</sub> =3.6V, V <sub>OUT</sub> =5.0V I <sub>LOAD</sub> =50mA to 500mA			0.6%	(Vomax-vomin)/ vomin
V.	LBI voltage threshold		475	500	525	mV
V <sub>LBI</sub> LBI input hysteresis				35		mV

Publication Date: Jun. 2012 Revision: 1.2 4/15



- Note 1: Absolute maximum ratings indicate limits beyond which damage may occur.
- Note 2: All voltages are in respect to the potential of the ground pin.
- **Note 3:**  $\theta$  JA is measured in the natural convection at  $T_A=25^{\circ}C$  on a highly effective thermal conductivity test board (2 layers, 2SOP).
- **Note 4:**  $\theta_{JC}$  represents the thermal resistance between the chip and the top of the package case.
- Note 5: Maximum power dissipation for the device is calculated using the following equation:

$$P_D = \frac{T_J(MAX) - T_A}{\theta_{JA}}$$

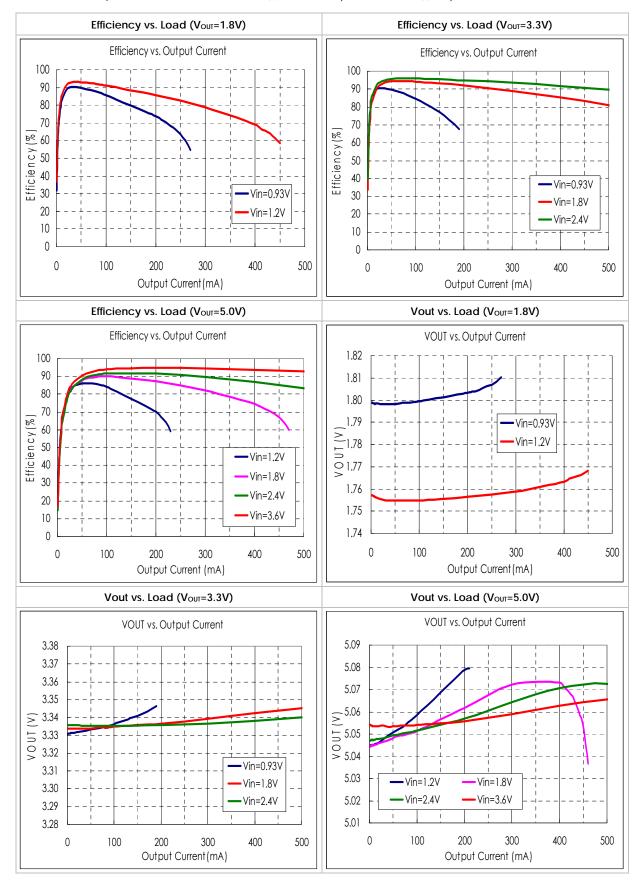
Where  $T_J(MAX)$  is the maximum junction temperature,  $T_A$  is the ambient temperature, and  $\theta_{JA}$  is the junction-to-ambient thermal resistance. For example, for the TDFN-10 package  $\theta_{JA}$  = 110°C/W,  $T_J$  (MAX) = 150°C and using  $T_A$  = 25°C, the maximum power dissipation is 1.136W. The derating factor (-1/ $\theta_{JA}$ ) = -9.09mW/°C. Below 25°C the power dissipation figure can be increased by 9.09mW per degree and similarly decreased by this factor for temperatures above 25°C.

Note 6: Typical values represent the most typical parametric norm.

Publication Date: Jun. 2012 Revision: 1.2 5/15

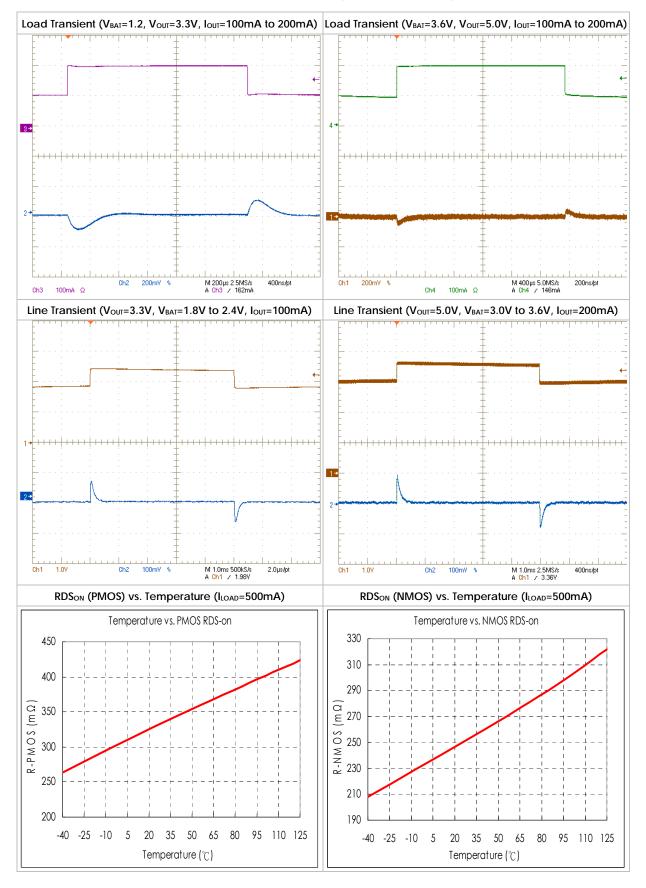
#### **Typical Performance Characteristics**

Unless otherwise specified,  $V_{BAT}=1.2V$ ,  $V_{EN}=1.2V$ ,  $V_{OUT}=3.3V$ ,  $L=6.8\mu H$ ,  $C_{IN}=10 u F$ ,  $C_{out}=47 \mu F$  and  $T_A=25 ^{\circ} C$ 



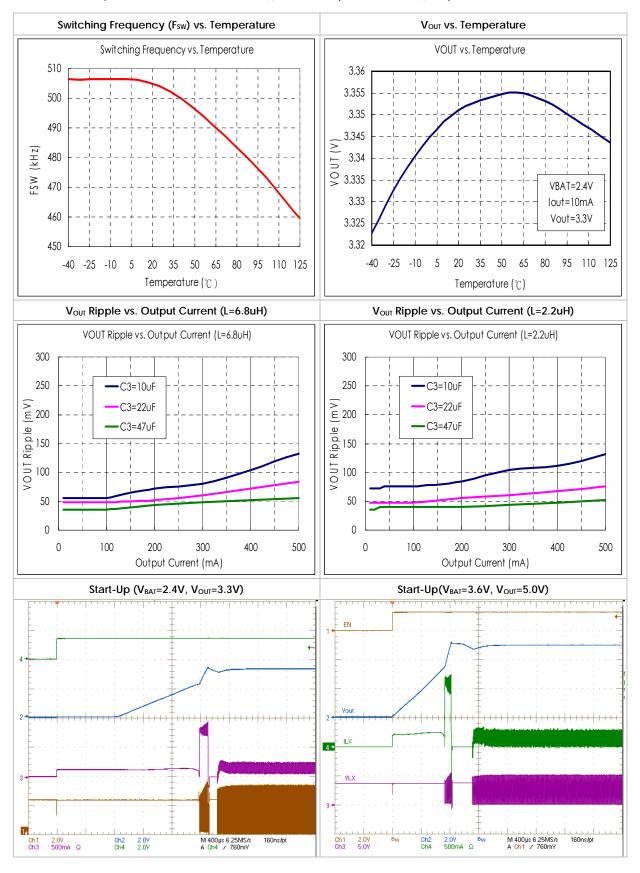
#### Typical Performance Characteristics (cont.)

Unless otherwise specified,  $V_{BAT}=1.2V$ ,  $V_{EN}=1.2V$ ,  $V_{OUT}=3.3V$ ,  $L=6.8\mu H$ ,  $C_{IN}=10 u F$ ,  $C_{out}=47 \mu F$  and  $T_A=25 ^{\circ} C$ 



#### Typical Performance Characteristics (cont.)

Unless otherwise specified,  $V_{BAT}$ =1.2V,  $V_{EN}$ =1.2V,  $V_{OUT}$ =3.3V, L=6.8 $\mu$ H,  $C_{IN}$ =10 $\nu$ F,  $C_{out}$ =47 $\mu$ F and  $T_A$ =25 $^{\circ}$ C



#### **Application Information**

#### **Detailed Description**

The EMH7020 is a high efficiency, synchronous fixed frequency, current-mode step-up DC/DC converter. During shutdown mode, the output is completely isolated from the input without drawing any battery current. The device can provide up to 500mA output current and maintains at least 90% efficiency from two-cell alkaline batteries. With Synchronous structure, an external Schottky diode is not needed.

During normal operation, the internal oscillator sends a pulse signal to set latch and turn on/off internal NMOSFET/PMOSFET during each clock cycle. A current sense voltage sums NMOSFET current and slope signal connected to the negative terminal of the PWM comparator. When this signal voltage exceeds output voltage of error amplifier, the PWM comparator will send a signal to reset latch and turn off/on internal NMOSFET/PMOSFET. The output voltage of error amplifier is magnified from the difference between reference voltage and feedback voltage. If reference voltage is higher than feedback voltage, more current is delivered to the output, otherwise, less current is delivered.

#### Enable/Disable

The EMH7020 enters shutdown mode when EN pin voltage is less 0.4V ( $V_{BAT}$  or  $V_{OUT} > 1.8V$ ). When in shutdown mode, all internal circuits of the EMH7020 are turn off and quiescent current is reduced to 1uA. When driver EN pin voltage is higher than 0.9V ( $V_{BAT}$  or  $V_{OUT} > 1.8V$ ), start-up begins.

During  $V_{BAT}$  or  $V_{OUT}$  <1.8V, the EN pin voltage should be less than 0.2  $V_{BAT}$  to disable the device, otherwise, the EN pin voltage should be higher than 0.9  $V_{BAT}$  to enable the device.

#### Low Battery Detection ---- LBI/LBO

The EMH7020 provides an on-chip comparator with 35mV internal hysteresis for low battery detection. If the LBI pin voltage falls below the internal reference voltage (0.5V.), the LBO pin (an open-drain output) sinks current to GND. The LBI pin should be connected to BAT pin if the low battery comparator is not used.

#### **OTP**

The internal thermal sensor turns off internal NMOSFET/PMOSFET when junction temperature is exceeded  $150^{\circ}$ C, the OTP is designed with a  $35^{\circ}$ C hysteresis.

Publication Date: Jun. 2012 Revision: 1.2 9/15

#### **Pre-Boost Current and Short Circuit Protect**

Initially output voltage is lower than battery voltage, and the EMH7020 enters pre-boost phase. During pre-boost phase, the internal NMOSFET/PMOSFET is turned off/on and a constant current is provided from battery to output until the output voltage close to the battery voltage. The constant current is limited by internal controller. If the output short to ground, the EMH7020 also limits the output current to avoid damage condition. Figure 2 shows the typical pre-boost current vs. output voltage for specific battery voltages:

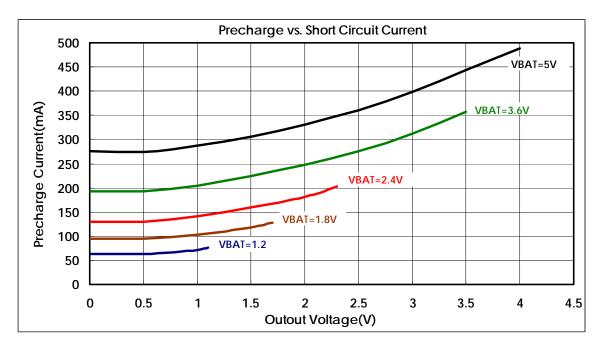


FIG.2 Short circuit current during pre-boost phase

#### Selecting the Output Voltage

The output voltage is set using the FB pin and a resistor divider connected to OUT, FB, and GND. The feedback pin voltage typical is 0.5V, The Vout can be calculated by the following equation:

$$R3 = R4[(V_{OUT}/V_{FR})-1]$$
 (1)

Where  $V_{\text{REF}} \!\!=\!\! 0.5 V$  and  $V_{\text{OUT}}$  ranges from 1.8V to 5.5V.

The recommended table:

Table 1

V <sub>OUT</sub>	R3	R4
5.5V	1.02ΜΩ	102ΚΩ
3.3V	1.02ΜΩ	182ΚΩ
1.8V	510ΚΩ	200ΚΩ

#### **Inductor Selection**

The Inductor is required to force the output voltage higher while being driven by a lower input voltage. For most applications, a 6.8uH inductor is used. An inductor with higher peak inductor current tends to provide a higher output voltage ripple (IPEAK \* output filter capacitor ESR). The inductor's DC resistance can significantly affect efficiency. The maximum output current can be calculated as follows:

$$I_{\text{OUT(max)}} = \frac{V_{\text{BAT}}}{V_{\text{OUT}}} [I_{\text{CL}} - \text{Toff}(\frac{V_{\text{OUT}} - V_{\text{BAT}}}{2 \times L})] \eta \tag{2}$$

 $I_{OUT(max)}$  = Maximum loading  $V_{BAT}$  = Input voltage L = Inductor value in  $\mu H$   $\eta$  = efficiency (~ 0.9 typically) Toff = LX switch's off - time in  $\mu s$ 

 $I_{CI} = 1.5A$ 

Table 2

VENDOR	SERIES	VALUE	ISAT	DCR
Sumida	CDRH5D28R	6.8µH	1.5A	37mΩ
EPCOS	B82462-G4	6.8µH	1.65A	51mΩ
WURTH ELEKTRONIK	7447789	6.8µH	2.75A	44mΩ

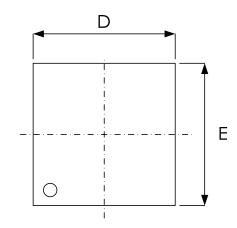
#### **Input Capacitor Selection**

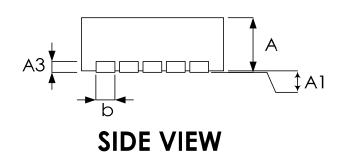
A low ESR 10µF input capacitor is recommended to improve transient behavior and reduce the peak current drawn from the battery. Ceramic capacitors are also a good choice for input decoupling and should be located as close as possible to the device.

#### **Output Capacitor Selection**

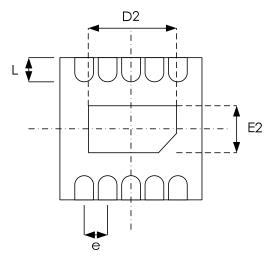
The output ripple voltage relates with the peak inductor current and the output capacitor's ESR. Multilayer ceramic capacitors are an excellent choice as they have extremely low ESR. A 47µF output capacitor is sufficient for most applications.

# Package Outline Drawing TDFN-10 (3x3 mm)





# **TOP VIEW**



# **BOTTOM VIEW**

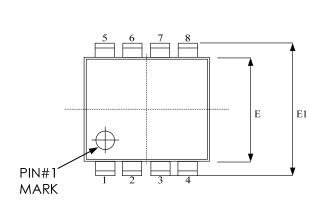
C1 1	Dimension in mm		
Symbol	Min	Max	
А	0.70	0.85	
A1	0.00	0.05	
A3	0.18	0.25	
Ъ	0.18	0.30	
D	2.95	3.05	
Е	2.95	3.05	
е	0.5 BSC		
L	0.30	0.50	

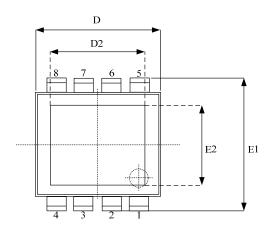
Exposed pad

	Dimension	on in mm
	Min	Max
D2	2.20	2.70
E2	1.40	1.75

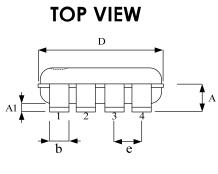
# ESMT/EMP

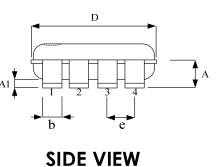
#### E-MSOP-8L

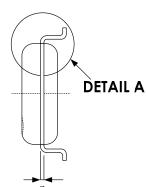


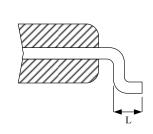


### **BOTTOM VIEW**









**DETAIL A** 

C11	Dimension in mm		
Symbol	Min	Max	
А	0.81	1.10	
A1	0.00	0.15	
ь	0.22	0.38	
С	0.08	0.23	
D	2.90	3.10	
Е	2.90	3.10	
E1	4.80	5.00	
е	0.65 BSC		
L	0.40	0.80	

Exposed pad

	Dimension in mm	
	Min	Max
D2	1.42	1.78
E2	1.38	1.73

Publication Date: Jun. 2012 Revision: 1.2 13/15

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### **Revision History**

Revision	Date	Description
0.1	2010.08.27	Original
0.2	2010.11.11	The Fig.2 "Precharge Current" unit is mA
0.3	2010.12.07	1.LBI voltage threshold update 2.V <sub>IH</sub> / V <sub>IL</sub> (as V <sub>BAT</sub> or V <sub>OUT</sub> <1.8V) update
0.4	2011.02.11	VOUT divider resistor is incorrect, the recommended table 1, R4 Value is 200 $\!\mathrm{K}\Omega$
1.0	2011.04.06	Skip "Preliminary"
1.1	2011.07.14	1.Add E-MSOP-8L package option     2.Revise TDFN3x3-10 outline drawing
1.2	2012.06.29	1.Modify the typical application     2.Modify the Condition of ISD     3.Modify the Package Outline Drawing

Publication Date: Jun. 2012 Revision: 1.2 14/15

## ESMT/EMP

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Publication Date: Jun. 2012 Revision: 1.2 15/15